1 Features

- Input voltage range: 0.5 V to 5.5 V
- 1.8-V Minimum input voltage for start-up
- Output voltage setting range: 2.2 V to 5.5 V
- Two 47-mΩ (LS) / 68-mΩ (HS) MOSFETs
- 3.7-A Valley switching current limit
- 94% Efficiency at $V_{IN} = 3.6$ V, $V_{OUT} = 5$ V and $I_{OUT} = 1.5$ A
- 1-MHz Switching frequency when $V_{IN} > 1.5$ V and 0.5-MHz switching frequency when $V_{IN} < 1$ V
- Typical 0.1µA shutdown current from Vin and SW
- ±2.5% Reference voltage accuracy over −40°C to +125°C
- Auto PFM operation mode at light load
- Pass-through mode when $V_{IN} > V_{OUT}$
- True disconnection between input and output during shutdown
- Output overvoltage and thermal shutdown protections
- Output short-circuit protection
- 1.2-mm × 1.6-mm SOT563 (DRL) 6-pin package

2 Applications

- Electronic shelf label
- Video doorbell
- Remote controller

3 Description

TPS61023 device is a synchronous boost converter with 0.5-V ultra-low input voltage. The device provides a power supply solution for portable equipment and smart devices powered by various batteries and super capacitors. The TPS61023 has typical 3.7-A valley switch current limit over full temperature range. With a wide input voltage range of 0.5 V to 5.5 V, the TPS61023 supports super capacitor backup power applications, which may deeply discharge the super capacitor.

The TPS61023 operates at 1-MHz switching frequency when the input voltage is above 1.5 V. The switching frequency decreases gradually to 0.5 MHz when the input voltage is below 1.5 V down to 1 V. The TPS61023 enters power-save mode at light load condition to maintain high efficiency over the entire load current range. The TPS61023 consumes a 20-µA quiescent current from $V_{OUT}$ in light load condition. During shutdown, the TPS61023 is completely disconnected from the input power and only consumes a 0.1-µA current to achieve long battery life. The TPS61023 has 5.7-V output overvoltage protection, output short circuit protection, and thermal shutdown protection.

The TPS61023 offers a very small solution size with 1.2-mm × 1.6-mm SOT563 (DRL) package and minimum amount of external components.

Device Information (1)

<table>
<thead>
<tr>
<th>PART NUMBER</th>
<th>PACKAGE</th>
<th>BODY SIZE (NOM)</th>
</tr>
</thead>
<tbody>
<tr>
<td>TPS61023</td>
<td>SOT563 (6)</td>
<td>1.20 mm × 1.60 mm</td>
</tr>
</tbody>
</table>

(1) For all available packages, see the orderable addendum at the end of the data sheet.

![Typical Application Circuit](image-url)
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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Original (September 2019) to Revision A

Page

• Changed Product Status to Production Data for Production release ......................................................... 1
5 Pin Configuration and Functions

<table>
<thead>
<tr>
<th>PIN</th>
<th>I/O</th>
<th>DESCRIPTION</th>
</tr>
</thead>
<tbody>
<tr>
<td>NO.</td>
<td>NAME</td>
<td>DESCRIPTION</td>
</tr>
<tr>
<td>1</td>
<td>FB</td>
<td>Voltage feedback of adjustable output voltage.</td>
</tr>
<tr>
<td>2</td>
<td>EN</td>
<td>Enable logic input. Logic high voltage enables the device. Logic low voltage disables the device and turns it into shutdown mode.</td>
</tr>
<tr>
<td>3</td>
<td>VIN</td>
<td>IC power supply input.</td>
</tr>
<tr>
<td>4</td>
<td>GND</td>
<td>Ground pin of the IC.</td>
</tr>
<tr>
<td>5</td>
<td>SW</td>
<td>The switch pin of the converter. It is connected to the drain of the internal low-side power MOSFET and the source of the internal high-side power MOSFET.</td>
</tr>
<tr>
<td>6</td>
<td>VOUT</td>
<td>Boost converter output.</td>
</tr>
</tbody>
</table>
6 Specifications

6.1 Absolute Maximum Ratings
over operating free-air temperature range (unless otherwise noted)\(^{(1)}\)

<table>
<thead>
<tr>
<th>Parameter</th>
<th>MIN</th>
<th>MAX</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>Voltage range at terminals(^{(2)})</td>
<td>-0.3</td>
<td>7</td>
<td>V</td>
</tr>
<tr>
<td>VIN, EN, FB, SW, VOUT</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>SW spike at 10ns</td>
<td>-0.7</td>
<td>8</td>
<td>V</td>
</tr>
<tr>
<td>SW spike at 1ns</td>
<td>-0.7</td>
<td>9</td>
<td>V</td>
</tr>
<tr>
<td>Operating junction temperature, T(_J)</td>
<td>-40</td>
<td>150</td>
<td>°C</td>
</tr>
<tr>
<td>Storage temperature, T(_stg)</td>
<td>-65</td>
<td>150</td>
<td>°C</td>
</tr>
</tbody>
</table>

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values are with respect to network ground terminal.

6.2 ESD Ratings

<table>
<thead>
<tr>
<th>Value</th>
<th>MIN</th>
<th>NOM</th>
<th>MAX</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001(^{(1)})</td>
<td>±2000</td>
<td></td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>Charged-device model (CDM), per JEDEC specification JESD22-C101(^{(2)})</td>
<td>±500</td>
<td></td>
<td></td>
<td>V</td>
</tr>
</tbody>
</table>

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 500-V HBM is possible with the necessary precautions. Pins listed as ±2000 V may actually have higher performance.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 250-V CDM is possible with the necessary precautions. Pins listed as ±500 V may actually have higher performance.

6.3 Recommended Operating Conditions
over operating free-air temperature range (unless otherwise noted)

<table>
<thead>
<tr>
<th>Parameter</th>
<th>MIN</th>
<th>NOM</th>
<th>MAX</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>Vin</td>
<td>0.5</td>
<td>5.5</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>V(_{OUT})</td>
<td>2.2</td>
<td>5.5</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>L</td>
<td>0.37</td>
<td>1.0</td>
<td>2.9</td>
<td>µH</td>
</tr>
<tr>
<td>C(_{IN})</td>
<td>1.0</td>
<td>4.7</td>
<td>µF</td>
<td></td>
</tr>
<tr>
<td>C(_{OUT})</td>
<td>4</td>
<td>10</td>
<td>1000</td>
<td>µF</td>
</tr>
<tr>
<td>T(_J)</td>
<td>-40</td>
<td></td>
<td>125</td>
<td>°C</td>
</tr>
</tbody>
</table>

6.4 Thermal Information

<table>
<thead>
<tr>
<th>Thermal Metric(^{(1)})</th>
<th>TPS61023 DRL (SOT563) - 6 PINS</th>
<th>TPS61023 DRL (SOT563) - 6 PINS</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>R(_{JA})</td>
<td>142.7</td>
<td>91.4</td>
<td>°C/W</td>
</tr>
<tr>
<td>R(_{JC})</td>
<td>55.7</td>
<td>N/A</td>
<td>°C/W</td>
</tr>
<tr>
<td>R(_{NB})</td>
<td>31.0</td>
<td>N/A</td>
<td>°C/W</td>
</tr>
<tr>
<td>(\Psi)(_{JT})</td>
<td>1.4</td>
<td>5.3</td>
<td>°C/W</td>
</tr>
<tr>
<td>(\Psi)(_{JB})</td>
<td>30.7</td>
<td>38.1</td>
<td>°C/W</td>
</tr>
</tbody>
</table>

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

(2) Measured on TPS61023EVM, 4-layer, 2oz copper 50mm×38mm PCB.
6.5 Electrical Characteristics

$T_J = -40°C$ to $125°C$, $V_{IN} = 3.6$ V and $V_{OUT} = 5.0$ V. Typical values are at $T_J = 25°C$ (unless otherwise noted).

<table>
<thead>
<tr>
<th>PARAMETER</th>
<th>TEST CONDITIONS</th>
<th>MIN</th>
<th>TYP</th>
<th>MAX</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>$V_{IN}$</td>
<td>Input voltage range</td>
<td>0.5</td>
<td>5.5</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>$V_{IN,UVLO}$</td>
<td>Under-voltage lockout threshold</td>
<td>$V_{IN}$ rising</td>
<td>1.7</td>
<td>1.8</td>
<td>V</td>
</tr>
<tr>
<td></td>
<td></td>
<td>$V_{IN}$ falling</td>
<td>0.4</td>
<td>0.5</td>
<td>V</td>
</tr>
<tr>
<td>$I_Q$</td>
<td>Quiescent current into VIN pin</td>
<td>$I_C$ enabled, No load, No switching $V_{IN} = 1.8$ V to 5.5 V, $V_{FB} = V_{REF} + 0.1$ V, $T_J$ up to 85°C</td>
<td>0.9</td>
<td>3.0</td>
<td>µA</td>
</tr>
<tr>
<td></td>
<td></td>
<td>$I_C$ enabled, No load, No switching $V_{OUT} = 2.2$ V to 5.5 V, $V_{FB} = V_{REF} + 0.1$ V, $T_J$ up to 85°C</td>
<td>20</td>
<td>30</td>
<td>µA</td>
</tr>
<tr>
<td>$I_{SD}$</td>
<td>Shutdown current into VIN and SW pin</td>
<td>$I_C$ disabled, $V_{IN} = V_{SW} = 3.6$ V, $T_J = 25°C$</td>
<td>0.1</td>
<td>0.2</td>
<td>µA</td>
</tr>
</tbody>
</table>

| OUTPUT | | | |
|-------|-----------------|-----|-----|-----|------|
| $V_{OUT}$ | Output voltage setting range | 2.2 | 5.5 | V |
| $V_{REF}$ | Reference voltage at the FB pin | PWM mode | 580 | 595 | 610 | mV |
|         |                  | PFM mode | 585 | 601 | mV |
| $V_{DVP}$ | Output over-voltage protection threshold | $V_{OUT}$ rising | 5.5 | 6.0 | V |
| $V_{DVP,HYS}$ | Over-voltage protection hysteresis | | 0.1 | V |
| $I_{FB,LKG}$ | Leakage current at FB pin | $T_J = 25°C$ | 4 | 20 | nA |
|           |                  | $T_J = 125°C$ | 6 | nA |
| $I_{VOUT,LKG}$ | Leakage current into VOUT pin | $I_C$ disabled, $V_{IN} = 0$ V, $V_{SW} = 0$ V, $V_{OUT} = 3.5$ V, $T_J = 25°C$ | 1 | 3 | µA |
| $t_{SS}$ | Soft startup time | From active EN to VOUT regulation, $V_{IN} = 2.5$ V, $V_{OUT} = 5.0$ V, $C_{OUT,EFF} = 10µF$, $I_{OUT} = 0$ | 700 | µs |

| POWER SWITCH | | | |
|--------------|-----------------|-----|-----|-----|------|
| $R_{DS(on)}$ | High-side MOSFET on resistance | $V_{OUT} = 5.0$ V | 68 | mΩ |
| Low-side MOSFET on resistance | $V_{OUT} = 5.0$ V | 47 | mΩ |
| $f_{SW}$ | Switching frequency | $V_{IN} = 3.6$ V, $V_{OUT} = 5.0$ V, PWM mode | 1.0 | MHz |
|           |                  | $V_{IN} = 1.0$ V, $V_{OUT} = 5.0$ V, PWM mode | 0.5 | MHz |
| $t_{ON,min}$ | Minimum on time | | 40 | 96 | 130 | ns |
| $t_{OFF,min}$ | Minimum off time | | 80 | 120 | ns |
| $I_{LIM,SW}$ | Valley current limit | $V_{IN} = 3.6$ V, $V_{OUT} = 5.0$ V | 2.7 | 3.7 | A |
| $I_{LIM,CHG}$ | Pre-charge current | $V_{IN} = 1.8$ - 5.5 V, $V_{OUT} < 0.4$ V | 200 | 350 | mA |
|           |                  | $V_{IN} = 2.4$ V, $V_{OUT} = 2.15$ V | 750 | 1200 | mA |

| LOGIC INTERFACE | | | |
|-----------------|-----------------|-----|-----|-----|------|
| $V_{EN,H}$ | EN logic high threshold | $V_{IN} > 1.8$ V or $V_{OUT} > 2.2$ V | 1.2 | V |
| $V_{EN,L}$ | EN logic low threshold | $V_{IN} > 1.8$ V or $V_{OUT} > 2.2$ V | 0.35 | 0.42 | 0.45 | V |

| PROTECTION | | | |
|------------|-----------------|-----|-----|-----|------|
| $T_{SD}$ | Thermal shutdown threshold | $T_J$ rising | 150 | °C |
| $T_{SD,HYS}$ | Thermal shutdown hysteresis | $T_J$ falling below $T_{SD}$ | 20 | °C |
6.6 Typical Characteristics

$V_{IN} = 3.6\text{ V}, V_{OUT} = 5\text{ V}, T_{J} = 25°C$, unless otherwise noted

![Figure 1. Load Efficiency With Different Input](image1)

![Figure 2. Load Efficiency With Different Output](image2)

![Figure 3. Load Regulation](image3)

![Figure 4. Pre-charge Current vs Output Voltage](image4)

![Figure 5. Reference Voltage vs Temperature](image5)

![Figure 6. Quiescent Current into VIN vs Temperature](image6)
Typical Characteristics (continued)

\( V_{IN} = 3.6 \, \text{V}, \, V_{OUT} = 5 \, \text{V}, \, T_J = 25^\circ \text{C}, \, \text{unless otherwise noted} \)

\begin{align*}
\text{Figure 7. Quiescent Current into } V_{OUT} \text{ vs Temperature} \\
\text{Figure 8. Shutdown Current vs Temperature} \\
\text{Figure 9. Switching Frequency vs Input Voltage} \\
\text{Figure 10. EN Rising Threshold vs Temperature} \\
\text{Figure 11. EN Falling Threshold vs Temperature}
\end{align*}

\( V_{IN} = 1.8 \, \text{V}; \, V_{OUT} = 2.2 \, \text{V}, \, 3.6 \, \text{V}, \, 5 \, \text{V}, \, T_J = -40^\circ \text{C to } +125^\circ \text{C}, \, \text{No switching} \)
7 Detailed Description

7.1 Overview
The TPS61023 synchronous step-up converter is designed to operate from an input voltage supply range between 0.5 V and 5.5 V with 3.7-A (typical) valley switch current limit. The TPS61023 typically operates at a quasi-constant frequency pulse width modulation (PWM) at moderate to heavy load currents. The switching frequency is 1 MHz when the input voltage is above 1.5 V. The switching frequency reduces down to 0.5 MHz gradually when the input voltage goes down from 1.5 V to 1 V and keeps at 0.5 MHz when the input voltage is below 1 V. At light load conditions, the TPS61023 converter operates in power-save mode with pulse frequency modulation (PFM). During PWM operation, the converter uses adaptive constant on-time valley current mode control scheme to achieve excellent line regulation and load regulation and allows the use of a small inductor and ceramic capacitors. Internal loop compensation simplifies the design process while minimizing the number of external components.

7.2 Functional Block Diagram
7.3 Feature Description

7.3.1 Undervoltage Lockout

The TPS61023 has a built-in undervoltage lockout (UVLO) circuit to ensure the device working properly. When the input voltage is above the UVLO rising threshold of 1.8 V, the TPS61023 can be enabled to boost the output voltage. After the TPS61023 starts up and the output voltage is above 2.2 V, the TPS61023 works with input voltage as low as 0.5 V.

7.3.2 Enable and Soft Start

When the input voltage is above the UVLO rising threshold and the EN pin is pulled to a voltage above 1.2 V, the TPS61023 is enabled and starts up. At the beginning, the TPS61023 charges the output capacitors with a current of about 350 mA when the output voltage is below 0.4 V. When the output voltage is charged above 0.4 V, the output current is changed to having output current capability to drive the 2-Ω resistance load. After the output voltage reaches the input voltage, the TPS61023 starts switching, and the output voltage ramps up further. The typical start-up time is 700 μs accounting from EN high to output reaching target voltage for the application with input voltage is 2.5 V, output voltage is 5 V, output effective capacitance is 10 μF and no load. When the voltage at the EN pin is below 0.4 V, the internal enable comparator turns the device into shutdown mode. In the shutdown mode, the device is entirely turned off. The output is disconnected from input power supply.

7.3.3 Switching Frequency

The TPS61023 switches at a quasi-constant 1-MHz frequency when the input voltage is above 1.5 V. When the input voltage is lower than 1.5 V, the switching frequency is reduced gradually to 0.5 MHz to improve the efficiency and get higher boost ratio. When the input voltage is below 1 V, the switching frequency is fixed at a quasi-constant 0.5 MHz.

7.3.4 Current Limit Operation

The TPS61023 uses a valley current limit sensing scheme. Current limit detection occurs during the off-time by sensing of the voltage drop across the synchronous rectifier.

When the load current is increased such that the inductor current is above the current limit within the whole switching cycle time, the off-time is increased to allow the inductor current to decrease to this threshold before the next on-time begins (so called frequency fold-back mechanism). When the current limit is reached, the output voltage decreases during further load increase.

The maximum continuous output current ($I_{OUT(CL)}$), before entering current limit (CL) operation, can be defined by Equation 1.

$$I_{OUT(CL)} = (1-D) \times \left( I_{LIM} + \frac{1}{2} \Delta I_{L(P-P)} \right)$$

where

- $D$ is the duty cycle
- $\Delta I_{L(P-P)}$ is the inductor ripple current

The duty cycle can be estimated by Equation 2.

$$D = 1 - \frac{V_{IN} \times \eta}{V_{OUT}}$$

where

- $V_{OUT}$ is the output voltage of the boost converter
- $V_{IN}$ is the input voltage of the boost converter
- $\eta$ is the efficiency of the converter, use 90% for most applications

Figure 1: TPS61023 Typical Application Circuit Diagram

Figure 2: TPS61023 Efficiency vs. Load Current Graph
Feature Description (continued)

The peak-to-peak inductor ripple current is calculated by Equation 3.

\[ \Delta L_{(P-P)} = \frac{V_{IN} \times D}{L \times f_{SW}} \]

where

- \( L \) is the inductance value of the inductor
- \( f_{SW} \) is the switching frequency
- \( D \) is the duty cycle
- \( V_{IN} \) is the input voltage of the boost converter

(3)

7.3.5 Pass-Through Operation

When the input voltage is higher than the setting output voltage, the output voltage is higher than the target regulation voltage. When the output voltage is 101% of the setting target voltage, the TPS61023 stops switching and fully turns on the high-side PMOS FET. The device works in pass-through mode. The output voltage is the input voltage minus the voltage drop across the DCR of the inductor and the \( R_{DS(on)} \) of the PMOS FET. When the output voltage drops below the 97% of the setting target voltage as the input voltage declines or the load current increases, the TPS61023 resumes switching again to regulate the output voltage.

7.3.6 Overvoltage Protection

The TPS61023 has an output overvoltage protection (OVP) to protect the device if the external feedback resistor divider is wrongly populated. When the output voltage is above 5.7 V typically, the device stops switching. Once the output voltage falls 0.1 V below the OVP threshold, the device resumes operating again.

7.3.7 Output Short-to-Ground Protection

The TPS61023 starts to limit the output current when the output voltage is below 1.8 V. The lower the output voltage reaches, the smaller the output current is. When the VOUT pin is short to ground, and the output voltage becomes less than 0.4 V, the output current is limited to approximate 350 mA. Once the short circuit is released, the TPS61023 goes through the soft start-up again to the regulated output voltage.

7.3.8 Thermal Shutdown

The TPS61023 goes into thermal shutdown once the junction temperature exceeds 150°C. When the junction temperature drops below the thermal shutdown recovery temperature, typically 130°C, the device starts operating again.

7.4 Device Functional Modes

The TPS61023 has two switching operation modes, PWM mode in moderate to heavy load conditions and power save mode with pulse frequency modulation (PFM) in light load conditions.

7.4.1 PWM Mode

The TPS61023 uses a quasi-constant 1.0-MHz frequency pulse width modulation (PWM) at moderate to heavy load current. Based on the input voltage to output voltage ratio, a circuit predicts the required on-time. At the beginning of the switching cycle, the NMOS switching FET. The input voltage is applied across the inductor and the inductor current ramps up. In this phase, the output capacitor is discharged by the load current. When the on-time expires, the main switch NMOS FET is turned off, and the rectifier PMOS FET is turned on. The inductor transfers its stored energy to replenish the output capacitor and supply the load. The inductor current declines because the output voltage is higher than the input voltage. When the inductor current hits the valley current threshold determined by the error amplifier’s output, the next switching cycle starts again.

The TPS61023 has a built-in compensation circuit that can accommodate a wide range of input voltage, output voltage, inductor value and output capacitor value for stable operation.
Device Functional Modes (continued)

7.4.2 Power-Save Mode

The TPS61023 integrates a power-save mode with PFM to improve efficiency at light load. When the load current decreases, the inductor valley current set by the output of the error amplifier no longer regulates the output voltage. When the inductor valley current hits the low limit, the output voltage exceeds the setting voltage as the load current decreases further. When the FB voltage hits the PFM reference voltage, the TPS61023 goes into the power-save mode. In the power-save mode, when the FB voltage rises and hits the PFM reference voltage, the device continues switching for several cycles because of the delay time of the internal comparator — then it stops switching. The load is supplied by the output capacitor, and the output voltage declines. When the FB voltage falls below the PFM reference voltage, after the delay time of the comparator, the device starts switching again to ramp up the output voltage.

Figure 12. Output Voltage in PWM Mode and PFM Mode
8 Application and Implementation

NOTE
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information
The TPS61023 is a synchronous boost converter designed to operate from an input voltage supply range between 0.5 V and 5.5 V with a typically 3.7-A valley switch current limit. The TPS61023 typically operates at a quasi-constant 1-MHz frequency PWM at moderate-to-heavy load currents when the input voltage is above 1.5 V. The switching frequency changes to 0.5 MHz gradually with the input voltage changing from 1.5 V to 1 V for better efficiency and high step-up ratio. When the input voltage is below 1 V, the switching frequency is fixed at a quasi-constant 0.5 MHz. At light load currents, the TPS61023 converter operates in power-save mode with PFM to achieve high efficiency over the entire load current range.

8.2 Typical Application
The TPS61023 provides a power supply solution for portable devices powered by batteries or backup applications powered by super-capacitors. With typical 3.7-A switch current capability, the TPS61023 can output 5 V and 1.5 A from a single-cell Li-ion battery.

![Diagram of Li-ion Battery to 5-V Boost Converter](image)

Figure 13. Li-ion Battery to 5-V Boost Converter

8.2.1 Design Requirements
The design parameters are listed in Table 1.

<table>
<thead>
<tr>
<th>PARAMETERS</th>
<th>VALUES</th>
</tr>
</thead>
<tbody>
<tr>
<td>Input voltage</td>
<td>2.7 V to 4.35 V</td>
</tr>
<tr>
<td>Output voltage</td>
<td>5 V</td>
</tr>
<tr>
<td>Output current</td>
<td>1.5 A</td>
</tr>
<tr>
<td>Output voltage ripple</td>
<td>±50 mV</td>
</tr>
</tbody>
</table>
8.2.2 Detailed Design Procedure

8.2.2.1 Setting the Output Voltage

The output voltage is set by an external resistor divider (R1, R2 in Figure 13). When the output voltage is regulated, the typical voltage at the FB pin is \( V_{\text{REF}} \). Thus the resistor divider is determined by Equation 4.

\[
R1 = \left( \frac{V_{\text{OUT}}}{V_{\text{REF}}} - 1 \right) \times R2
\]

where
- \( V_{\text{OUT}} \) is the regulated output voltage
- \( V_{\text{REF}} \) is the internal reference voltage at the FB pin

For the best accuracy, should be kept R2 smaller than 300 k\( \Omega \) to ensure the current flowing through R2 is at least 100 times larger than the FB pin leakage current. Changing R2 towards a lower value increases the immunity against noise injection. Changing the R2 towards a higher value reduces the quiescent current for achieving highest efficiency at low load currents.

8.2.2.2 Inductor Selection

Because the selection of the inductor affects steady-state operation, transient behavior, and loop stability, the inductor is the most important component in power regulator design. There are three important inductor specifications, inductor value, saturation current, and dc resistance (DCR).

The TPS61023 is designed to work with inductor values between 0.37 \( \mu \)H and 2.9 \( \mu \)H. Follow Equation 5 to Equation 7 to calculate the inductor peak current for the application. To calculate the current in the worst case, use the minimum input voltage, maximum output voltage, and maximum load current of the application. To have enough design margins, choose the inductor value with –30% tolerances, and low power-conversion efficiency for the calculation.

In a boost regulator, the inductor dc current can be calculated by Equation 5.

\[
I_{\text{L(DC)}} = \frac{V_{\text{OUT}} \times I_{\text{OUT}}}{V_{\text{IN}} \times \eta}
\]

where
- \( V_{\text{OUT}} \) is the output voltage of the boost converter
- \( I_{\text{OUT}} \) is the output current of the boost converter
- \( V_{\text{IN}} \) is the input voltage of the boost converter
- \( \eta \) is the power conversion efficiency, use 90% for most applications

The inductor ripple current is calculated by Equation 6.

\[
\Delta I_{\text{L(P-P)}} = \frac{V_{\text{IN}} \times D}{L \times f_{\text{SW}}}
\]

where
- \( D \) is the duty cycle, which can be calculated by Equation 2
- \( L \) is the inductance value of the inductor
- \( f_{\text{SW}} \) is the switching frequency
- \( V_{\text{IN}} \) is the input voltage of the boost converter

Therefore, the inductor peak current is calculated by Equation 7.

\[
I_{\text{L(P)}} = I_{\text{L(DC)}} + \frac{\Delta I_{\text{L(P-P)}}}{2}
\]

Normally, it is advisable to work with an inductor peak-to-peak current of less than 40% of the average inductor current for maximum output current. A smaller ripple from a larger valued inductor reduces the magnetic hysteresis losses in the inductor and EMI. But in the same way, load transient response time is increased. The saturation current of the inductor must be higher than the calculated peak inductor current. Table 2 lists the recommended inductors for the TPS61023.
### 8.2.2.3 Output Capacitor Selection

The output capacitor is mainly selected to meet the requirements for output ripple and loop stability. The ripple voltage is related to capacitor capacitance and its equivalent series resistance (ESR). Assuming a ceramic capacitor with zero ESR, the minimum capacitance needed for a given ripple voltage can be calculated by Equation 8.

\[
C_{OUT} = \frac{I_{OUT} \times D_{MAX}}{f_{SW} \times V_{ripples}}
\]

where
- \(D_{MAX}\) is the maximum switching duty cycle
- \(V_{ripples}\) is the peak-to-peak output ripple voltage
- \(I_{OUT}\) is the maximum output current
- \(f_{SW}\) is the switching frequency

The ESR impact on the output ripple must be considered if tantalum or aluminum electrolytic capacitors are used. The output peak-to-peak ripple voltage caused by the ESR of the output capacitors can be calculated by Equation 9.

\[
V_{ripples,ESR} = L(P) \times R_{ESR}
\]

Take care when evaluating the derating of a ceramic capacitor under dc bias voltage, aging, and ac signal. For example, the dc bias voltage can significantly reduce capacitance. A ceramic capacitor can lose more than 50% of its capacitance at its rated voltage. Therefore, always leave margin on the voltage rating to ensure adequate capacitance at the required output voltage. Increasing the output capacitor makes the output ripple voltage smaller in PWM mode.

TI recommends using the X5R or X7R ceramic output capacitor in the range of 4-μF to 1000-μF effective capacitance. The output capacitor affects the small signal control loop stability of the boost regulator. If the output capacitor is below the range, the boost regulator can potentially become unstable. Increasing the output capacitor makes the output ripple voltage smaller in PWM mode.

### 8.2.2.4 Loop Stability, Feedforward Capacitor Selection

When the switching waveform shows large duty cycle jitter or the output voltage or inductor current shows oscillations, the regulation loop may be unstable.

The load transient response is another approach to check the loop stability. During the load transient recovery time, \(V_{OUT}\) can be monitored for settling time, overshoot or ringing that helps judge the stability of the converters. Without any ringing, the loop has usually more than 45° of phase margin.

A feedforward capacitor (C3 in the Figure 14) in parallel with R1 induces a pair of zero and pole in the loop transfer function. By setting the proper zero frequency, the feedforward capacitor can increase the phase margin to improve the loop stability. For large output capacitance more than 40 μF application, TI recommends a feedforward capacitor to set the zero frequency (\(f_{FFZ}\)) to 1 kHz. As for the input voltage lower than 1-V application, TI recommends to use the effective output capacitance is about 100 μF and set the zero frequency (\(f_{FFZ}\)) to 1 kHz. The value of the feedforward capacitor can be calculated by Equation 10.
\[ C_3 = \frac{1}{2\pi f_{FFZ} R_1} \]

where

- \( R_1 \) is the resistor between the VOUT pin and FB pin
- \( f_{FFZ} \) is the zero frequency created by the feedforward capacitor

(10)

**Figure 14. TPS61023 Circuit With Feedforward Capacitor**

**8.2.2.5 Input Capacitor Selection**

Multilayer X5R or X7R ceramic capacitors are excellent choices for the input decoupling of the step-up converter as they have extremely low ESR and are available in small footprints. Input capacitors must be located as close as possible to the device. While a 10-\( \mu F \) input capacitor is sufficient for most applications, larger values may be used to reduce input current ripple without limitations. Take care when using only ceramic input capacitors. When a ceramic capacitor is used at the input and the power is being supplied through long wires, a load step at the output can induce ringing at the VIN pin. This ringing can couple to the output and be mistaken as loop instability or could even damage the part. In this circumstance, place additional bulk capacitance (tantalum or aluminum electrolytic capacitor) between ceramic input capacitor and the power source to reduce ringing that can occur between the inductance of the power source leads and ceramic input capacitor.
### 8.2.3 Application Curves

**Figure 15. Switching Waveform at Heavy Load**

- **V**<sub>IN</sub> = 3.6 V, **V**<sub>OUT</sub> = 5 V, **I**<sub>OUT</sub> = 1 A

**Figure 16. Switching Waveform at Light Load**

- **V**<sub>IN</sub> = 3.6 V, **V**<sub>OUT</sub> = 5 V, **I**<sub>OUT</sub> = 50 mA

**Figure 17. Start-up Waveform**

- **V**<sub>IN</sub> = 3.6 V, **V**<sub>OUT</sub> = 5 V, 5-Ω resistance load

**Figure 18. Shutdown Waveform**

- **V**<sub>IN</sub> = 3.6 V, **V**<sub>OUT</sub> = 5 V, 5-Ω resistance load

**Figure 19. Load Transient**

- **V**<sub>IN</sub> = 3.6 V, **V**<sub>OUT</sub> = 5 V, **I**<sub>OUT</sub> = 80 mA to 1.5 A with 20-μs slew rate

**Figure 20. Line Transient**

- **V**<sub>IN</sub> = 2.7 V to 4.35 V with 20-μs slew rate, **V**<sub>OUT</sub> = 5 V, **I**<sub>OUT</sub> = 1 A
9 Power Supply Recommendations

The device is designed to operate from an input voltage supply range between 0.5 V to 5.5 V. This input supply must be well regulated. If the input supply is located more than a few inches from the converter, additional bulk capacitance may be required in addition to the ceramic bypass capacitors. A typical choice is a tantalum or aluminum electrolytic capacitor with a value of 100 μF. Output current of the input power supply must be rated according to the supply voltage, output voltage, and output current of the TPS61023.
10 Layout

10.1 Layout Guidelines

As for all switching power supplies, especially those running at high switching frequency and high currents, layout is an important design step. If the layout is not carefully done, the regulator could suffer from instability and noise problems. To maximize efficiency, switch rise and fall time are very fast. To prevent radiation of high frequency noise (for example, EMI), proper layout of the high-frequency switching path is essential. Minimize the length and area of all traces connected to the SW pin, and always use a ground plane under the switching regulator to minimize interplane coupling. The input capacitor needs not only to be close to the VIN pin, but also to the GND pin in order to reduce input supply ripple.

The most critical current path for all boost converters is from the switching FET, through the rectifier FET, then the output capacitors, and back to ground of the switching FET. This high current path contains nanosecond rise and fall time and must be kept as short as possible. Therefore, the output capacitor not only must be close to the VOUT pin, but also to the GND pin to reduce the overshoot at the SW pin and VOUT pin.

For better thermal performance, TI suggest to make copper polygon connected with each pin bigger.

10.2 Layout Example

![Layout Example Diagram]

Figure 25. Layout Example
10.3 Thermal Considerations

Restrict the maximum IC junction temperature to 125°C under normal operating conditions. Calculate the maximum allowable dissipation, \( P_{D\text{(max)}} \), and keep the actual power dissipation less than or equal to \( P_{D\text{(max)}} \). The maximum-power-dissipation limit is determined using Equation 11.

\[
P_{D\text{(max)}} = \frac{125 - T_A}{R_{\theta JA}}
\]

where

- \( T_A \) is the maximum ambient temperature for the application
- \( R_{\theta JA} \) is the junction-to-ambient thermal resistance given in Thermal Information

(11)

The TPS61023 comes in a SOT563 package. The real junction-to-ambient thermal resistance of the package greatly depends on the PCB type, layout. Using larger and thicker PCB copper for the power pads (GND, SW, and VOUT) to enhance the thermal performance. Using more vias connects the ground plate on the top layer and bottom layer around the IC without solder mask also improves the thermal capability.
11 Device and Documentation Support

11.1 Device Support

11.1.1 Third-Party Products Disclaimer
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11.5 Electrostatic Discharge Caution
These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

11.6 Glossary
SLYZ022 — TI Glossary.
This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information
The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.
### PACKAGING INFORMATION

<table>
<thead>
<tr>
<th>Orderable Device</th>
<th>Status (1)</th>
<th>Package Type</th>
<th>Package Drawing</th>
<th>Pins</th>
<th>Package Qty</th>
<th>Eco Plan (2)</th>
<th>Lead/Ball Finish (6)</th>
<th>MSL Peak Temp (3)</th>
<th>Op Temp (°C)</th>
<th>Device Marking (4/5)</th>
<th>Samples</th>
</tr>
</thead>
<tbody>
<tr>
<td>TPS61023DRLR</td>
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<td>SOT-5X3</td>
<td>DRL</td>
<td>6</td>
<td>4000</td>
<td>Green (RoHS &amp; no Sb/Br)</td>
<td>SN</td>
<td>Level-1-260C-UNLIM</td>
<td>-40 to 125</td>
<td>1GI</td>
<td>Samples</td>
</tr>
<tr>
<td>TPS61023DRLT</td>
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<td>SOT-5X3</td>
<td>DRL</td>
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<td>SN</td>
<td>Level-1-260C-UNLIM</td>
<td>-40 to 125</td>
<td>1GI</td>
<td>Samples</td>
</tr>
</tbody>
</table>

(1) The marketing status values are defined as follows:

**ACTIVE**: Product device recommended for new designs.

**LIFEBUY**: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND**: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW**: Device has been announced but is not in production. Samples may or may not be available.

**OBsolete**: TI has discontinued the production of the device.

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**Green**: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

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NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
NOTES: (continued)

4. Publication IPC-7351 may have alternate designs.
5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

7. Board assembly site may have different recommendations for stencil design.
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